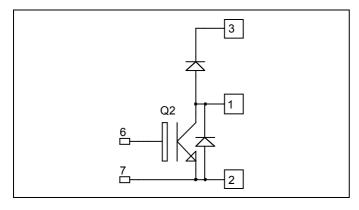


Boost chopper Trench + Field Stop IGBT3 Power Module



$$V_{CES} = 1200V$$

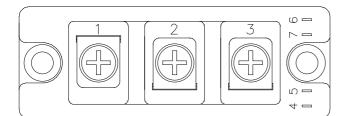
 $I_C = 150A$ @ $Tc = 80$ °C

Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- High level of integration
- M5 power connectors



Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
I_{C}	Continuous Collector Current	$T_C = 25$ °C	220	
	Continuous Conector Current	$T_C = 80$ °C	150	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	300	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	690	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	300A @ 1100V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				250	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	, GE 15.	$T_j = 25^{\circ}C$		1.7	2.1	V
			$T_j = 125$ °C		2.0		·
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 6 \text{ mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				600	nA

Dynamic Characteristics

•	Characteristic	Test Conditions	Test Conditions		Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			10.8		nF
C_{oes}	Output Capacitance	$V_{CE} = 25V$			0.56		
C_{res}	Reverse Transfer Capacitance	f = 1MHz			0.5		
Q_{G}	Gate charge	V _{GE} =±15V, I _C =150A V _{CE} =600V			1.4		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (25°C)		250		
T _r	Rise Time	$V_{GE} = \pm 15V$			90		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 150A$		550		ns	
T_{f}	Fall Time	$R_G = 4.7\Omega$		130			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 150A$ $R_{G} = 4.7\Omega$			300		ns
T_{r}	Rise Time				100		
$T_{d(off)}$	Turn-off Delay Time				650		
T_{f}	Fall Time				180		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		11		ma I
$\mathrm{E}_{\mathrm{off}}$	Turn off Energy	$I_C = 150A$ $R_G = 4.7\Omega$	$T_j = 125$ °C		26		mJ
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 900V$ $t_p \le 10 \mu s$; $T_i = 125 ^{\circ}C$			600		A

Chopper diode ratings and characteristics

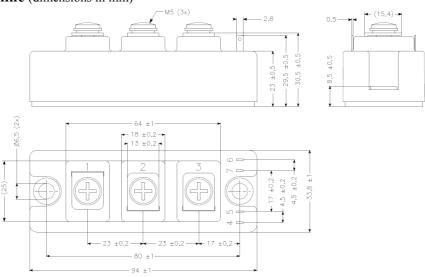
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_i = 25$ °C $T_i = 125$ °C			250 500	μА
I_{F}	DC Forward current		$Tc = 80^{\circ}C$		150	300	A
V_{F}	Diode Forward Voltage	$I_F = 150A$ $V_{GE} = 0V$	$T_i = 25^{\circ}C$		1.6	2.1	V
V F			$T_{i} = 125^{\circ}C$		1.6		v
t _{rr}	Reverse Recovery Time		$T_j = 25$ °C		250		ns
			$T_j = 125$ °C		350		
0	Davanga Dagayami Changa	$\begin{array}{l} I_F = 150A \\ V_R = 600V \\ di/dt = 3000A/\mu s \end{array}$	$T_i = 25^{\circ}C$		15		
Q_{rr}	Reverse Recovery Charge		$T_{i} = 125^{\circ}C$		29		μС
E _{rr}	Reverse Recovery Energy		$T_i = 25^{\circ}C$		7		m I
			$T_{j} = 125^{\circ}C$		12		mJ



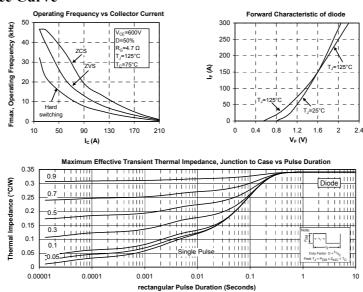
Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance IGBT Diode		IGBT			0.18	°C/W
			Diode			0.34	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	°C
T_{STG}	Storage Temperature Range			-40		125	
$T_{\rm C}$	Operating Case Temperature			-40		125	
Torque	Mounting torque For terminals To Heatsink	For terminals	M5	2		3.5	N.m
		M6	3		5	19.111	
Wt	Package Weight					180	g

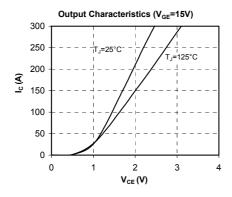
D1 Package outline (dimensions in mm)

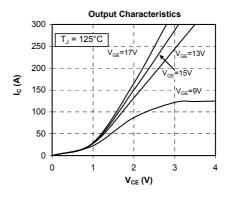


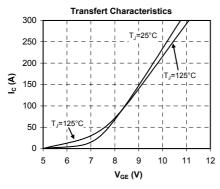
Typical Performance Curve

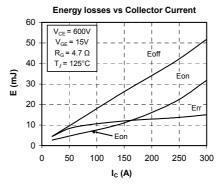


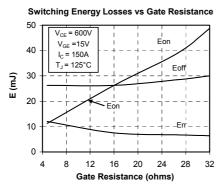


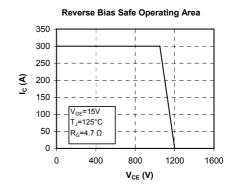


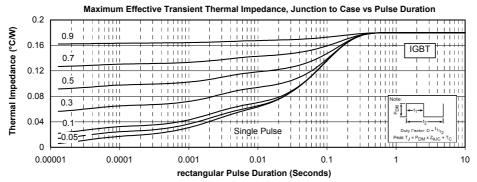












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